

FDT3N40 N-Channel UniFET[™] MOSFET

400 V, 2.0 A, 3.4

Features

- $R_{DS(on)} = 3.4 \ \Omega \text{ (Max.)} @ V_{GS} = 10 \text{ V}, I_D = 1.0 \text{ A}$
- Low Gate Charge (Typ. 4.5 nC)
- Low Crss (Typ. 3.7 pF)
- 100% Avalanche Tested

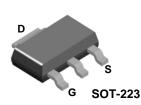
Applications

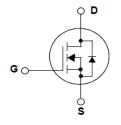
- LCD/LED TV
- Lighting
- Uninterruptible Power Supply



Description

UniFET[™] MOSFET is Fairchild Semiconductor[®]'s high voltage MOSFET family based on planar stripe and DMOS technology. This MOSFET is tailored to reduce on-state resistance, and to provide better switching performance and higher avalanche energy strength. This device family is suitable for switching power converter applications such as power factor correction (PFC), flat panel display (FPD) TV power, ATX and electronic lamp ballasts.





Absolute Maximum Ratings

Symbol	Parameter Drain-Source Voltage			FDT3N40	Unit V	
V _{DSS}				400		
I _D	Drain Current	- Continuous (T _C = 25° - Continuous (T _C = 100		2.0 * 1.2 *	A A	
I _{DM}	Drain Current	- Pulsed	(Note 1)	8.0 *	A	
V _{GSS}	Gate-Source voltage			±30	V	
E _{AS}	Single Pulsed Avalanche Energy		Single Pulsed Avalanche	(Note 2)	46	mJ
I _{AR}	Avalanche Current		(Note 1)	2	A	
E _{AR}	Repetitive Avalanch	e Energy	(Note 1)	0.2	mJ	
dv/dt	Peak Diode Recove	ry dv/dt	(Note 3)	4.5	V/ns	
P _D	Power Dissipation	(T _C = 25°C) - Derate above 25°C		2 0.02	W W/°C	
T _{J,} T _{STG}	Operating and Storage Temperature Range			-55 to +150	°C	
Τ _L	Maximum Lead Temperature for Soldering Purpose, 1/8" from Case for 5 Seconds		rpose,	300	°C	

Thermal Characteristics

Symbol	Parameter	FDT3N40	Unit	
R_{\thetaJA}^{*}	Thermal Resistance, Case-to-Sink Typ.	60	°C/W	
* Surface Mounted on JESD51-3 Board, T<0.1sec.				

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Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDT3N40	FDT3N40TF	SOT-223	330mm	12mm	4000

Electrical Characteristics T_c = 25°C unless otherwise noted

Symbol	Parameter	Conditions	Min.	Тур.	Max	Unit
Off Charac	teristics				1	1
BV _{DSS}	Drain-Source Breakdown Voltage	$V_{GS} = 0V, I_{D} = 250\mu A$	400			V
ΔBV _{DSS} / ΔT _J	Breakdown Voltage Temperature Coefficient	$I_D = 250 \mu A$, Referenced to $25^{\circ}C$		0.4		V/°C
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 400V, V_{GS} = 0V$ $V_{DS} = 320V, T_{C} = 125^{\circ}C$			1 10	μΑ μΑ
I _{GSSF}	Gate-Body Leakage Current, Forward	$V_{GS} = 30V, V_{DS} = 0V$			100	nA
I _{GSSR}	Gate-Body Leakage Current, Reverse	$V_{GS} = -30V, V_{DS} = 0V$			-100	nA
On Charac	teristics	•				4
V _{GS(th)}	Gate Threshold Voltage	$V_{DS} = V_{GS}, I_D = 250 \mu A$	3.0		5.0	V
R _{DS(on)}	Static Drain-Source On-Resistance	V _{GS} = 10V, I _D = 1A		2.8	3.4	Ω
9 _{FS}	Forward Transconductance	$V_{DS} = 40V, I_D = 1A$ (Note 4)		2		S
Dynamic C	haracteristics	•				4
C _{iss}	Input Capacitance	$V_{DS} = 25V, V_{GS} = 0V,$		173	225	pF
C _{oss}	Output Capacitance	f = 1.0MHz		30	40	pF
C _{rss}	Reverse Transfer Capacitance			3.7	6	pF
Switching	Characteristics					
t _{d(on)}	Turn-On Delay Time	V _{DD} = 200V, I _D = 2A		10	30	ns
t _r	Turn-On Rise Time	$R_{G} = 25\Omega$		30	70	ns
t _{d(off)}	Turn-Off Delay Time			10	30	ns
t _f	Turn-Off Fall Time	(Note 4, 5)		25	60	ns
Qg	Total Gate Charge	V _{DS} = 320V, I _D = 2A		4.5	6	nC
Q _{gs}	Gate-Source Charge	V _{GS} = 10V		1.2		nC
Q _{gd}	Gate-Drain Charge	(Note 4, 5)		2		nC
Drain-Sou	rce Diode Characteristics and Maximur	n Ratings			1	1
I _S	Maximum Continuous Drain-Source Diode Forward Current				2	Α
I _{SM}	Maximum Pulsed Drain-Source Diode Forward Current				8	Α
V _{SD}	Drain-Source Diode Forward Voltage	$V_{GS} = 0V, I_S = 2A$			1.4	V
t _{rr}	Reverse Recovery Time	$V_{GS} = 0V, I_S = 2A$		210		ns
Q _{rr}	Reverse Recovery Charge	dI _F /dt =100A/μs (Note 4)		0.75		μC

NOTES:

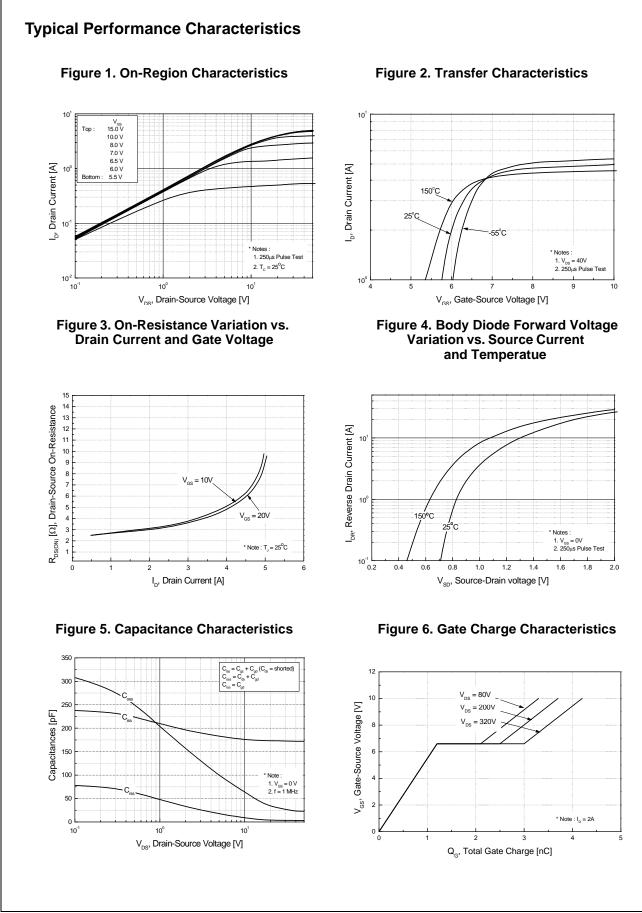
1. Repetitive Rating: Pulse width limited by maximum junction temperature

2. L = 10mH, I_{AS} = 2A, V_{DD} = 50V, R_G = 25 Ω , Starting T_J = 25°C

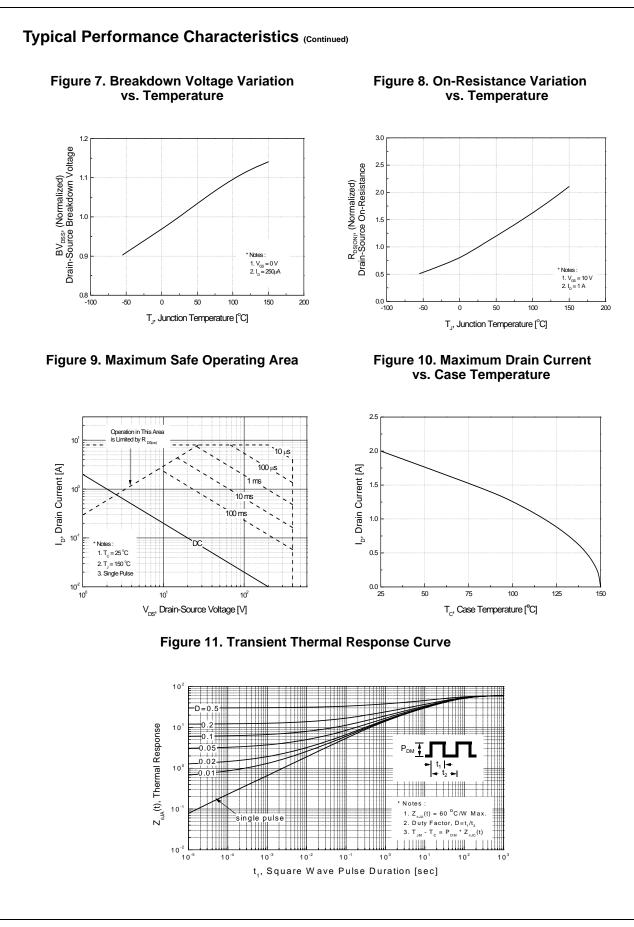
3. I_{SD} \leq 2A, di/dt \leq 200A/µs, V_{DD} \leq BV_{DSS}, Starting T_J = 25°C

4. Pulse Test: Pulse width $\leq 300 \mu \text{s}, \, \text{Duty Cycle} \leq 2\%$

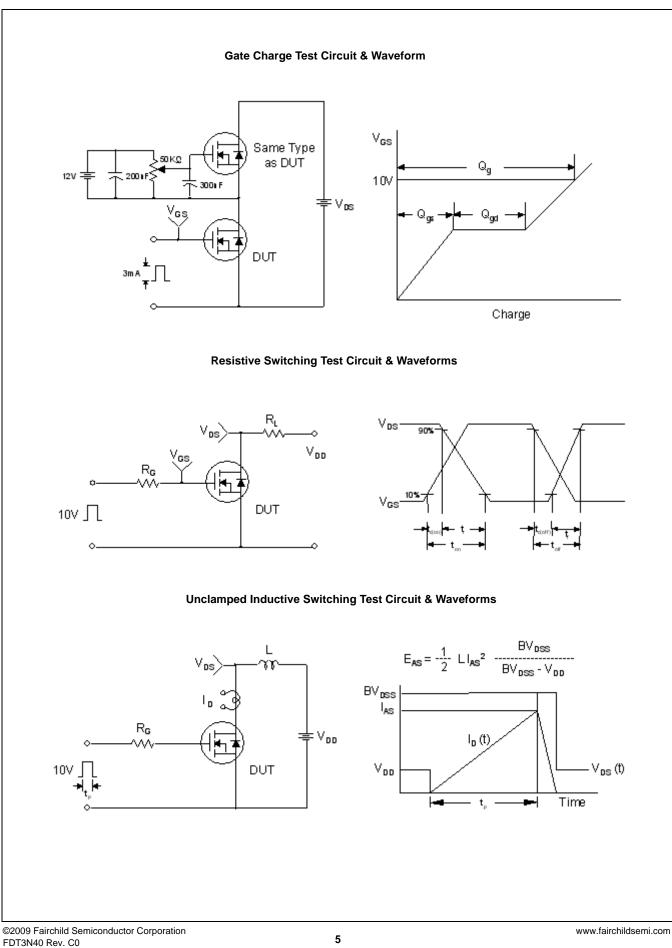
5. Essentially Independent of Operating Temperature Typical Characteristics

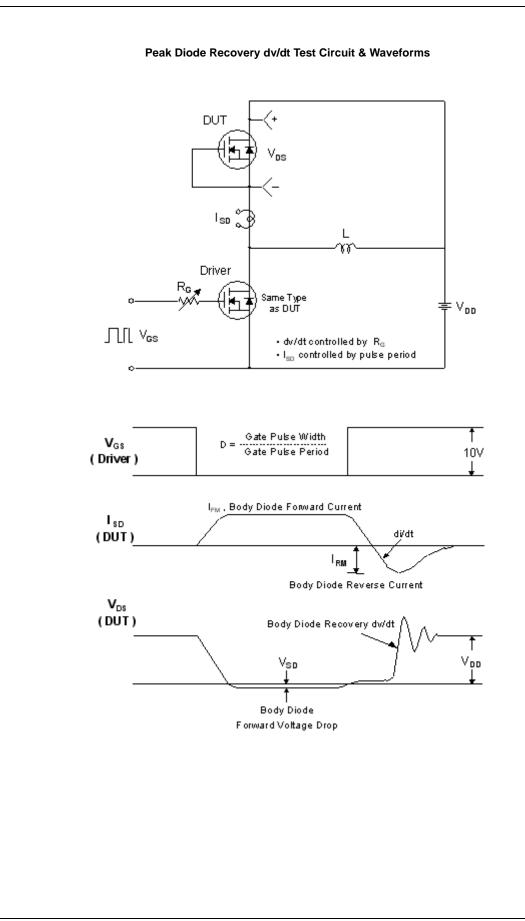


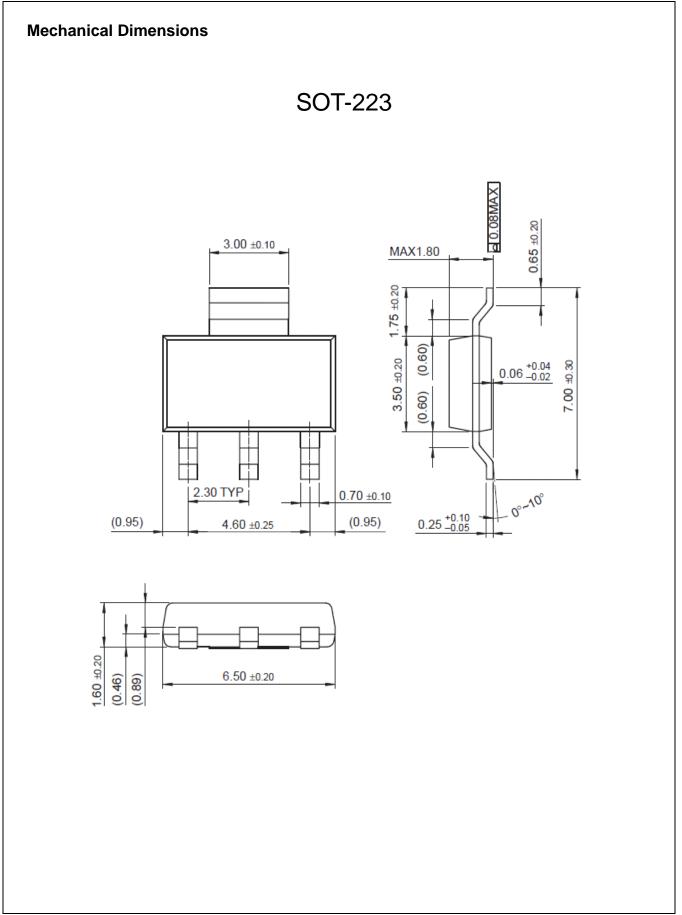
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